UNA0227 (UN227)

Transistor array to drive the small motor

Features

- Small and lightweight
- Low power consumption
- · Low-voltage drive
- With 8 elements incorporated

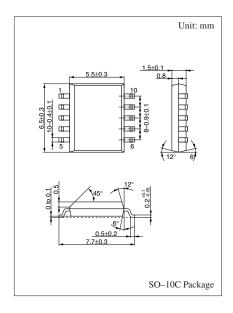
Applications

- For motor drives
- Small motor drive circuits in general

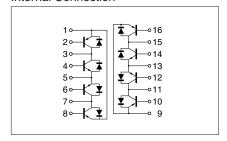
Absolute Maximum Ratings (Ta=25±3°C)

Parameter	Symbol	Ratings	Unit	
Collector to base voltage	V_{CBO}	±10	V	
Collector to emitter voltage	V _{CEO}	±10	V	
Emitter to base voltage	V_{EBO}	±7	V	
Collector current	I_C	±1.5	A	
Peak collector current	I_{CP}	±2	A	
Total power dissipation	P_T^*	0.5	W	
Junction temperature	T_{j}	150	°C	
Storage temperature	T_{stg}	-55 to +150	°C	

Note: \pm marks used above: +: NPN part, -: PNP part



Internal Connection



^{*} $T_C = 25$ °C only when the elements are active

■ Electrical Characteristics (Ta=25°C)

Parameter	Symbol	Conditions	min	typ	max	Unit	
Collector to base voltage	V _{CBO}	(NPN) $I_C = 10\mu A, I_E = 0$	10			V	
		(PNP) $I_C = -10\mu A, I_E = 0$	-10			\ \ \	
Collector to emitter voltage	V _{CEO}	(NPN) $I_C = 1 \text{mA}$, $I_B = 0$	10			V	
		(PNP) $I_C = -1 \text{ mA}, I_B = 0$	-10				
Emitter to base voltage	$V_{\rm EBO}$	(NPN) $I_E = 10\mu A, I_C = 0$	7			V	
		(PNP) $I_E = -10\mu A, I_C = 0$	-7				
Collector cutoff current	I_{CBO}	(NPN) $V_{CB} = 7V, I_{E} = 0$			1	μА	
		(PNP) $V_{CB} = -7V$, $I_E = 0$			-1		
Collector cutoff current	I_{CEO}	(NPN) $V_{CE} = 10V, I_{B} = 0$			2	μА	
		(PNP) $V_{CE} = -10V, I_B = 0$			-2		
Forward current transfer ratio	h _{FE}	(NPN) $V_{CE} = 1V$, $I_C = 400 \text{mA}^*$	200		700		
		(PNP) $V_{CE} = -1V$, $I_{C} = -400 \text{mA}$ *	200		700		
Collector to emitter saturation voltage	V _{CE(sat)}	(NPN) $I_C = 1A$, $I_B = 25mA*$			0.25	V	
		(PNP) $I_C = -1A$, $I_B = -25mA*$			- 0.35	v	
Transition frequency	f_T	(NPN) $V_{CB} = 6V$, $I_E = -50$ mA, $f = 200$ MHz		120		MHz	
		(PNP) $V_{CB} = -6V$, $I_E = 50mA$, $f = 200MHz$		120		MILIZ	
Collector output capacitance	C _{ob}	(NPN) $V_{CB} = 6V$, $I_E = 0$, $f = 1MHz$		25		pF	
		(NPN) $V_{CB} = -6V$, $I_E = 0$, $f = 1MHz$		35			
Forward voltage	V _F	(NPN) $I_F = 0.5A$			1.3	V	
		(PNP) $I_F = -0.5A$			-1.3	*	

^{*}Pulse measurement

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